

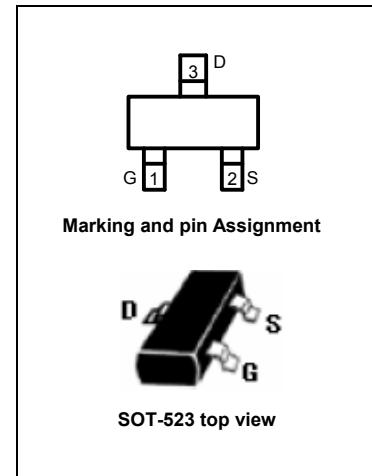
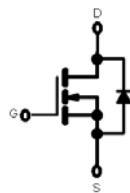
SOT-323 Plastic-Encapsulate MOSFETS

BSS138SR

N-Channel 50-V(D-S) MOSFET

FEATURE

- Low On-Resistance
- Low Gate Threshold Voltage
- Fast Switching Speed
- Low Input / Output Leakage



Maximum ratings ($T_a=25^\circ\text{C}$ unless otherwise noted)

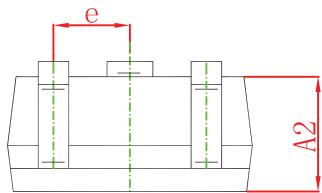
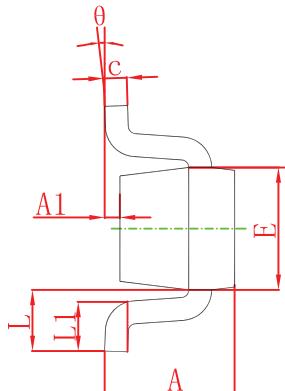
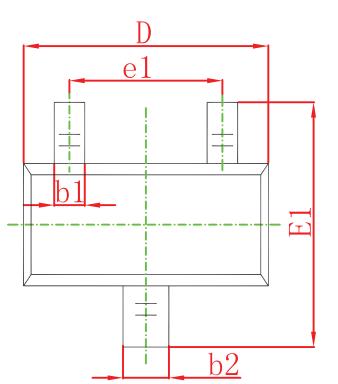
Parameter	Symbol	Value	Unit
Drain-Source Voltage	V_{DS}	50	V
Continuous Gate-Source Voltage	V_{GSS}	± 12	
Continuous Drain Current	I_D	0.34	A
Power Dissipation	P_D	0.35	W
Thermal Resistance from Junction to Ambient	$R_{\theta JA}$	357	°C/W
Operating Temperature	T_j	150	°C
Storage Temperature	T_{stg}	-55 ~ +150	

Electrical characteristics ($T_a=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Off characteristics						
Drain-source breakdown voltage	$V_{(\text{BR})\text{DSS}}$	$V_{GS} = 0V, I_D = 250\mu\text{A}$	50			V
Gate-body leakage	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 12V$			± 1	μA
		$V_{DS} = 0V, V_{GS} = \pm 10V$			± 0.5	μA
		$V_{DS} = 0V, V_{GS} = \pm 5V$			± 0.05	μA
Zero gate voltage drain current	I_{DSS}	$V_{DS} = 50V, V_{GS} = 0V$		0.1		μA
On characteristics						
Gate-threshold voltage	$V_{GS(\text{th})}$	$V_{DS} = V_{GS}, I_D = 0.25\text{mA}$	0.1	0.15	0.2	A
Static drain-source on-resistance	$R_{DS(\text{on})}$	$V_{GS} = 1.8V, I_D = 0.05\text{A}$				
		$V_{GS} = 2.5V, I_D = 0.05\text{A}$		1.20	3.0	Ω
		$V_{GS} = 5V, I_D = 0.05\text{A}$			1.6	
Forward transconductance	g_{FS}	$V_{DS} = 10V, I_D = 0.2\text{A}$	0.20			S
Dynamic characteristics*						
Input capacitance	C_{iss}	$V_{DS} = 25V, V_{GS} = 0V, f = 1\text{MHz}$		58		pF
Output capacitance	C_{oss}			9.75		
Reverse transfer capacitance	C_{rss}			5.2		
Gate resistance	R_G	$V_{DS} = 5V, V_{GS} = 10\text{mV}, f = 1\text{MHz}$		281		Ω
Switching characteristics*						
Turn-on delay time	$t_{d(on)}$	$V_{DD} = 30V, V_{DS} = 10V, I_D = 0.29A, R_{GEN} = 6\Omega$			5	ns
Rise time	t_r				5	
Turn-off delay time	$t_{d(off)}$				60	
Fall time	t_f				35	
Drain-source body diode characteristics						
Body diode forward voltage	V_{SD}	$I_S = 0.115A, V_{GS} = 0V$			1.2	V

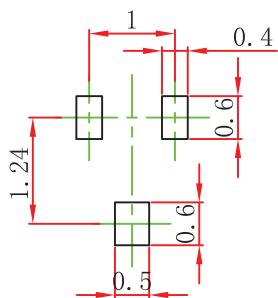
* These parameters have no way to verify.

SOT-523 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-523 Suggested Pad Layout



Note:

1. Controlling dimension: in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.